

BCP56-16

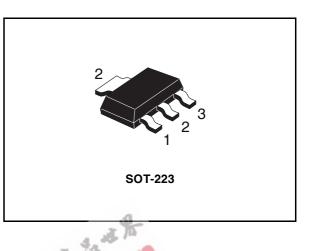
Low power NPN Transistor

General features

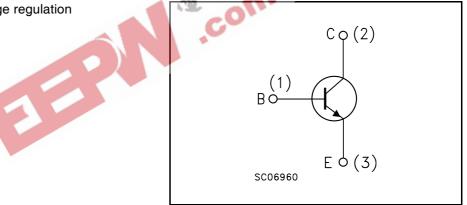
- Silicon epitaxial planar NPN medium voltage transistor
- SOT-223 plastic package for surface mounting circuits
- Available in tape & reel packing
- In compliance with the 2002/93/EC European Directive
- The PNP complementary type is BCP53-16

Applications

- Medium voltage load switch transistor
- Output stage for audio amplifiers circuits
- Automotive post-voltage regulation



Internal schematic diagram



Order codes

Part Number	Marking	Package	Packing
BCP56-16	BCP5616	SOT-223	Tape & reel

Contents

1	Electrical ratings
2	Electrical characteristics 4
	2.1 Electrical characteristics (curves) 5
3	Package mechanical data 6
4	Revision history





1

Electrical ratings

Table 1.	Absolute	maximum	rating
		maximani	

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	100	V
V_{CEO}	Collector-emitter voltage $(I_B = 0)$	80	V
V_{EBO}	Emitter-base voltage (I _C = 0)	5	V
۱ _C	Collector current	1	А
I _{CM}	Collector peak current (t _P < 5ms)	1.5	А
Ι _Β	Base current	0.1	А
I _{BM}	Base peak current (t _P < 5ms)	0.2	А
P _{tot}	Total dissipation at T _{amb} = 25°C	1.6	W
T _{stg}	Storage temperature	-65 to 150	°C
Т _Ј	Max. operating junction temperature	150	°C

Table 2. Thermal data

Table 2.	Thermal data	n	
Symbol	Parameter	Value	Unit
R _{thj-amb}	Thermal resistance junction-ambient (1) max	78	°C/W

1. Device mounted on PCB area of 1 cm².

2 Electrical characteristics

($T_{case} = 25^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	$V_{CB} = 30V$ $V_{CB} = 30V$; $T_j = 125^{\circ}C$			100 10	nA μA
V _{(BR)CEO} ⁽²⁾	Collector-emitter breakdown voltage (I _B =0)	I _C = 20mA	80			V
V _{(BR)CBO}	Collector-base breakdown voltage (I _E =0)	I _C = 100μA	100			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C =0)	I _E = 10μA	5			V
V _{CE(sat)} ⁽²⁾	Collector-emitter saturation voltage	I _C = 500mA I _B = 50mA	-		0.5	V
V _{BE(on)} ⁽²⁾	Base-emitter on voltage	I _C = 500mA V _{CE} = 2V			1	V
h _{FE} ⁽²⁾	DC current gain	$I_{C} = 5mA$ $V_{CE} = 2V$ $I_{C} = 150mA$ $V_{CE} = 2V$ $I_{C} = 500mA$ $V_{CE} = 2V$	40 100 25		250	

 Table 3.
 Electrical characteristics

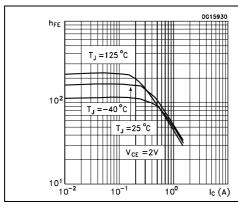
Note (2) Pulsed duration = $300 \ \mu s$, duty cycle $\leq 1.5\%$



2.1 Electrical characteristics (curves)

Figure 1. DC current gain

Figure 2. Collector-emitter saturation



voltage

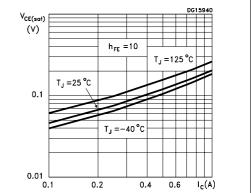
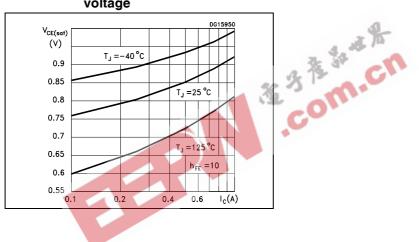


Figure 3. Base-emitter saturation voltage



3 Package mechanical data

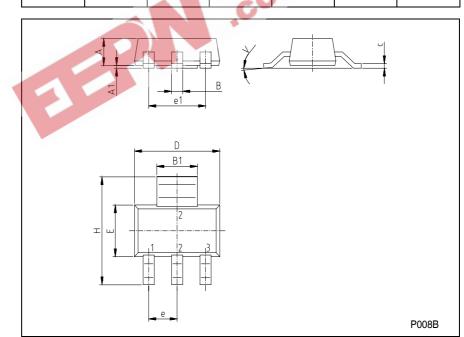
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com





	SOT-223 MECHANICAL DATA					
DIM.	mm			inch		
Dim.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			1.80			0.071
В	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
с	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
е		2.30			0.090	
e1		4.60			0.181	
Е	3.30	3.50	3.70	0.130	0.138	0.146
н	6.70	7.00	7.30	0.264	0.276	0.287
V			10°	5.0		10 [°]
A1		0.02	SIL O			







4 Revision history

Table 4.	Revision	history
----------	----------	---------

Date	Revision	Changes
02-Sep-2004	1	Initial release.
26-May-2006	2	New template
14-Jun-2006	3	Three curves has been added on page 5.



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT DESIGNED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

